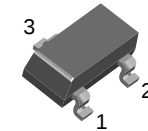


Small Signal Diode

BAS31



SOT-23
CASE 318BM

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)
(Note 1, 2)

Symbol	Parameter	Ratings	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage	120	V
$I_{F(AV)}$	Average Rectified Forward Current	200	mA
I_{FSM}	Non-Repetitive Peak Forward Surge Current	Pulse Width = 1.0 second	1.0
		Pulse Width = 1.0 microsecond	2.0
T_{STG}	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
T_J	Operating Junction Temperature	150	$^\circ\text{C}$

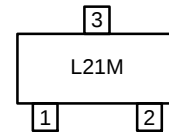
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- These ratings are based on a maximum junction temperature of 150°C .
- These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty-cycle operations.

THERMAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

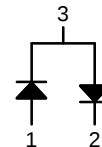
Symbol	Parameter	Ratings	Unit
P_D	Power Dissipation	350	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	357	

MARKING DIAGRAM



L21 = Specific Device Code
M = Date Code

CONNECTION DIAGRAM



ORDERING INFORMATION

Device	Package	Reel	Shipping [†]
BAS31	SOT-23 3L (Pb-Free, Halide Free)	7"	3000 / Tape & Reel
BAS31-D87Z		13"	10000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Max	Unit
V_R	Breakdown Voltage	$I_R = 1.0 \text{ mA}$	120	–	V
V_F	Forward Voltage	$I_F = 10 \text{ mA}$	–	750	mV
		$I_F = 50 \text{ mA}$	–	840	mV
		$I_F = 100 \text{ mA}$	–	900	mV
		$I_F = 200 \text{ mA}$	–	1.00	V
		$I_F = 400 \text{ mA}$	–	1.25	V
I_R	Reverse Current	$V_R = 90 \text{ V}$	–	100	nA
		$V_R = 90 \text{ V}, T_A = 150^\circ\text{C}$	–	100	μA
C_T	Total Capacitance	$V_R = 0 \text{ V}, f = 1.0 \text{ MHz}$	–	35	pF
t_{rr}	Reverse Recovery Time	$I_F = I_R = 30 \text{ mA}, I_{RR} = 3.0 \text{ mA}, R_L = 100 \Omega$	–	50	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL PERFORMANCE CHARACTERISTICS

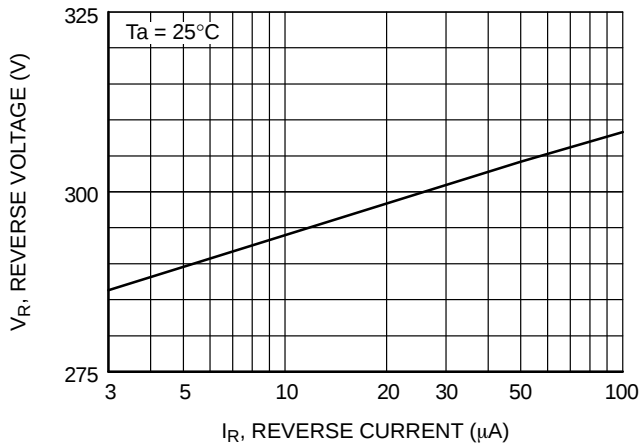
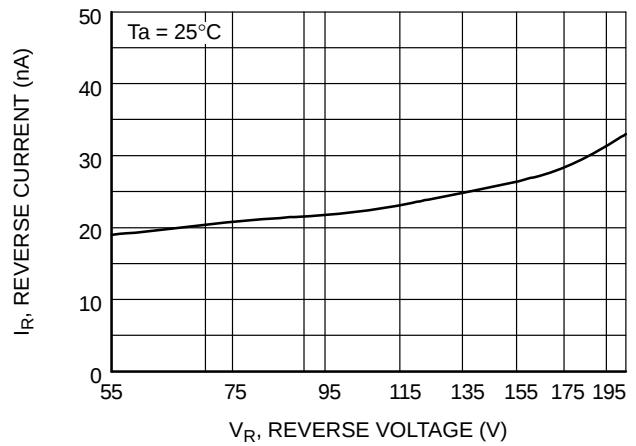
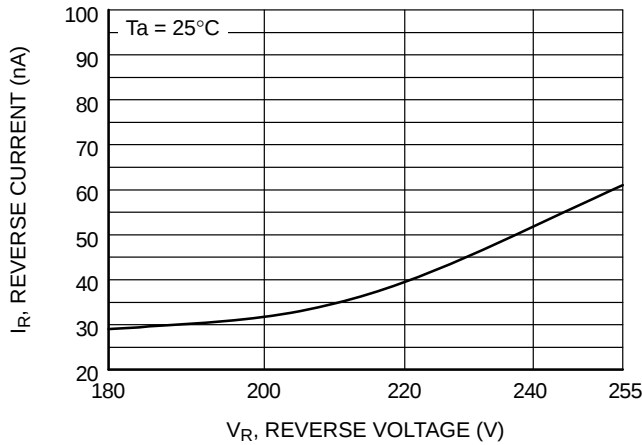


Figure 1. Reverse Voltage vs. Reverse Current BV – 1.0 to 100 μA



GENERAL RULE: The Reverse Current of a diode will approximately double for every ten (10) Degree C increase in Temperature

Figure 2. Reverse Current vs. Reverse Voltage I_R – 55 to 205 V



GENERAL RULE: The Reverse Current of a diode will approximately double for every ten (10) Degree C increase in Temperature

Figure 3. Reverse Current vs. Reverse Voltage I_R – 180 to 255 V

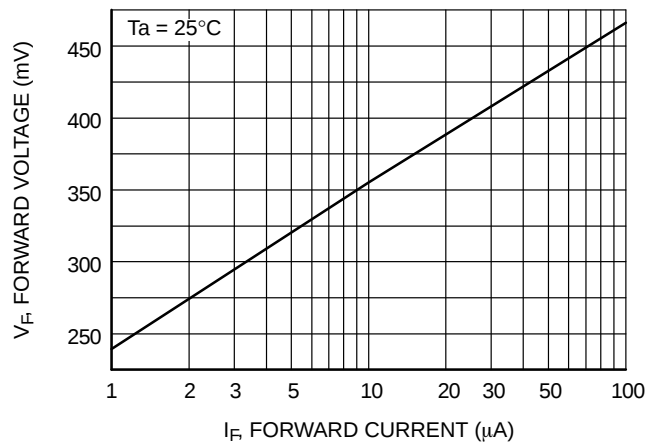


Figure 4. Forward Voltage vs. Forward Current V_F – 1.0 to 100 μA

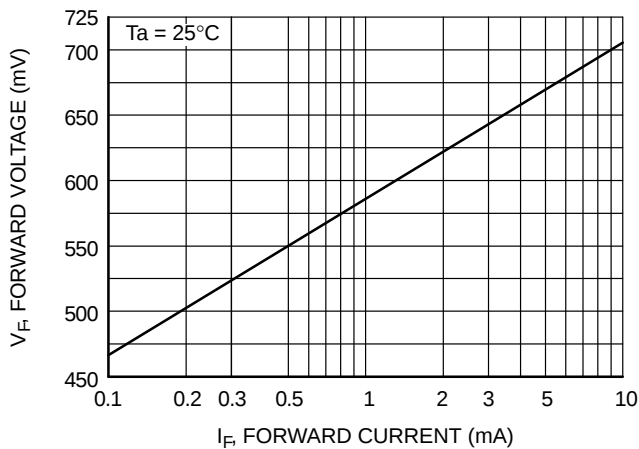


Figure 5. Forward Voltage vs. Forward Current V_F – 0.1 to 10 mA

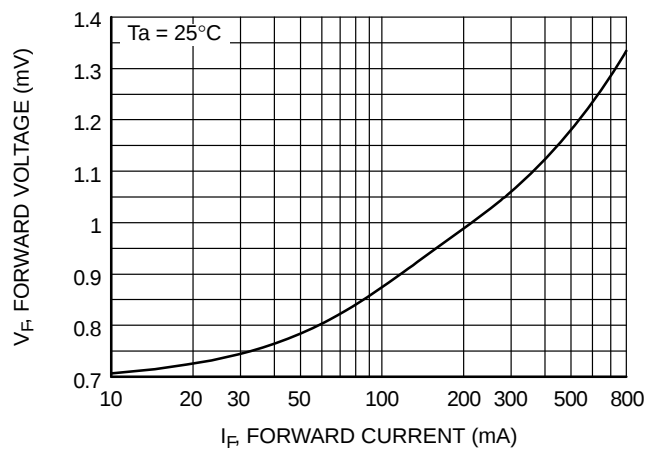


Figure 6. Forward Voltage vs. Forward Current V_F – 10 to 800 mA

TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)

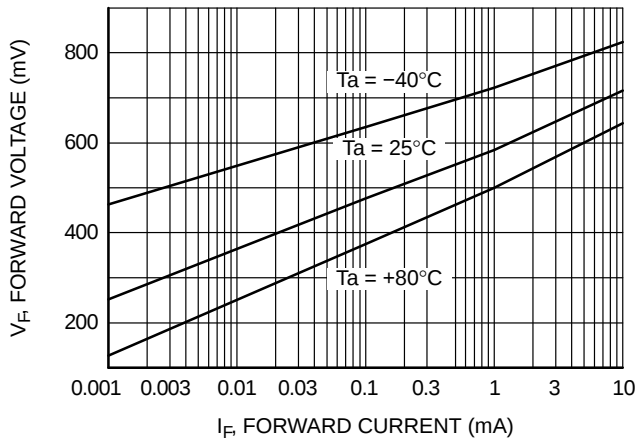


Figure 7. Forward Voltage vs. Ambient Temperature
 $V_F - 1.0 \mu\text{A} - 10 \text{ mA} (-40 \text{ to } +80^\circ\text{C})$

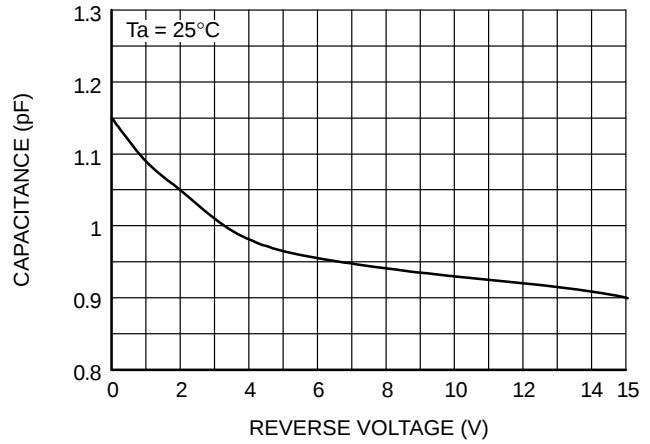


Figure 8. Capacitance vs. Reverse Voltage

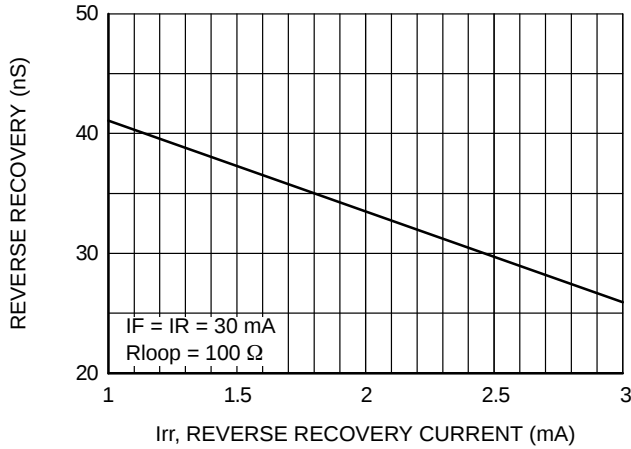


Figure 9. Reverse Recovery Time vs. Reverse Recovery Current (I_{rr})

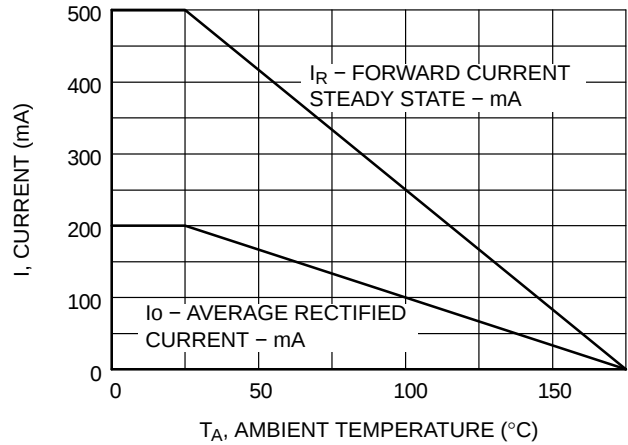


Figure 10. Average Rectified Current (I_O) and Forward Current (I_F) vs. Ambient Temperature (T_A)

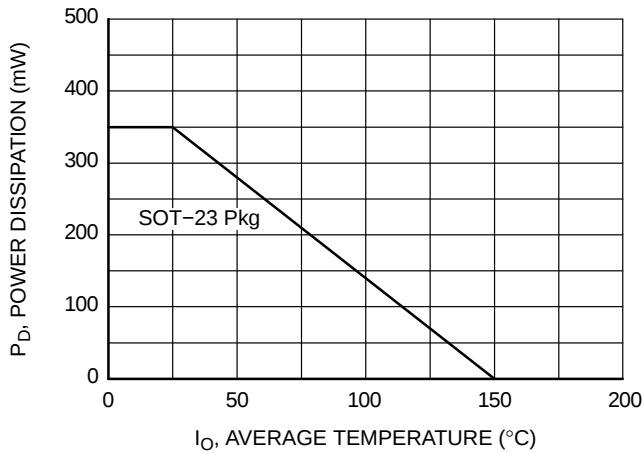


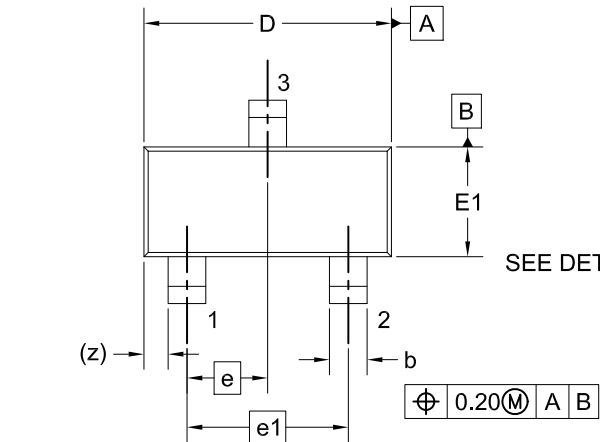
Figure 11. Power Derating Curve

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

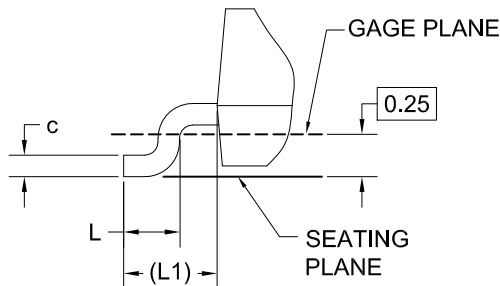
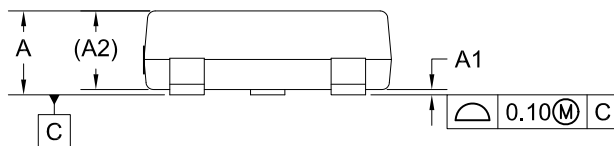
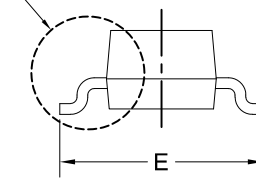


SOT-23 CASE 318BM ISSUE A

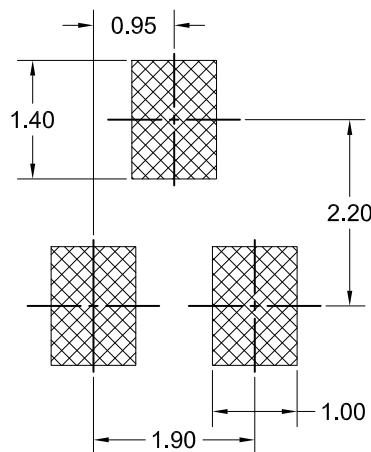
DATE 01 SEP 2021



SEE DETAIL A



DETAIL A
SCALE: 2X



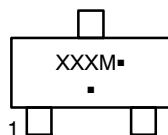
**LAND PATTERN
RECOMMENDATION**

NOTES: UNLESS OTHERWISE SPECIFIED

- A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
- D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 2009.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	---	---	1.20
A1	0.00	0.05	0.10
A2	0.93 REF		
b	0.37	0.44	0.60
c	0.08	0.15	0.23
D	2.72	2.92	3.12
E	2.10	2.40	2.70
E1	1.15	1.30	1.50
e	0.95 BSC		
e1	1.90 BSC		
L	0.20	---	---
L1	0.55 REF		
z	0.29 REF		

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERM/D.

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